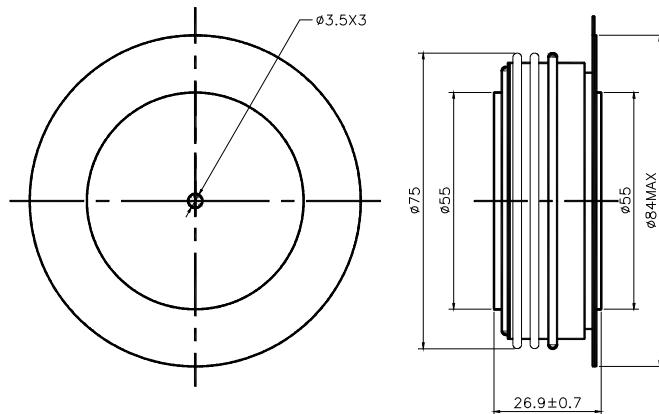


SYMBOL	CHARACTERISTIC	TEST CONDITIONS	$T_j$ (°C)	VALUE			UNIT
				Min	Type	Max	
$I_{F(AV)}$	Mean forward current	180° half sine wave 50Hz Double side cooled, $T_{hs}=55^\circ C$	150			2815	A
$I_{F(AV)}$	Mean forward current	180° half sine wave 50Hz Double side cooled, $T_{hs}=90^\circ C$	150			2072	A
$V_{RRM}$	Repetitive peak reverse voltage	$V_{RRM}$ tp=10ms $V_{RsM} = V_{RRM} + 100V$	150	1100		2000	V
$I_{RRM}$	Repetitive peak current	at $V_{RRM}$	150			100	mA
$I_{FSM}$	Surge forward current	10ms half sine wave $V_R=0.6V_{RRM}$	150			36.6	KA
$I^2T$	$I^2T$ for fusing coordination					6696	$A^2s \times 10^3$
$V_{FO}$	Threshold voltage		150			0.78	V
$r_F$	Forward slop resistance					0.13	$m\Omega$
$V_{FM}$	Peak on-state voltage	$I_{TM}=4500A, F=26KN$	150			1.37	V
$I_{rm}$	Reverse recovery current	$I_{TM}=1000A, tp=1000\mu s,$ $di/dt=-40A/\mu s, V_R=50V$	150			140	A
$t_{rr}$	Reverse recovery time					6.0	$\mu s$
$Q_{rr}$	Recovery charge					420	$\mu C$
$R_{th(j-h)}$	Thermal resistance Junction to heatsink	At 180° sine double side cooled Clamping force 26KN				0.020	$^\circ C / W$
$F_m$	Mounting force				21	30	KN
$T_{stg}$	Stored temperature			-40		160	$^\circ C$
$W_t$	Weight					620	g
Outline		ZT54cT55					

## Outline



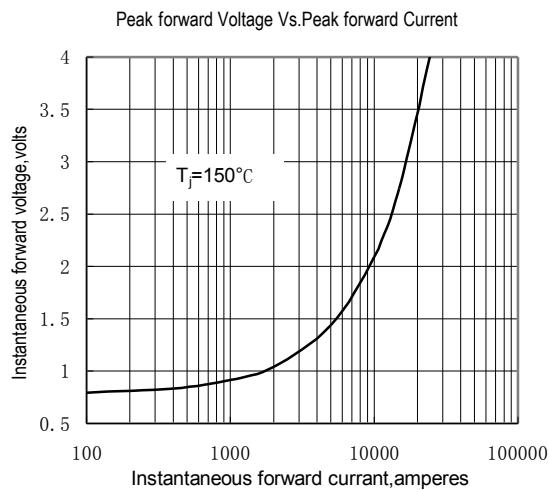


Fig.1

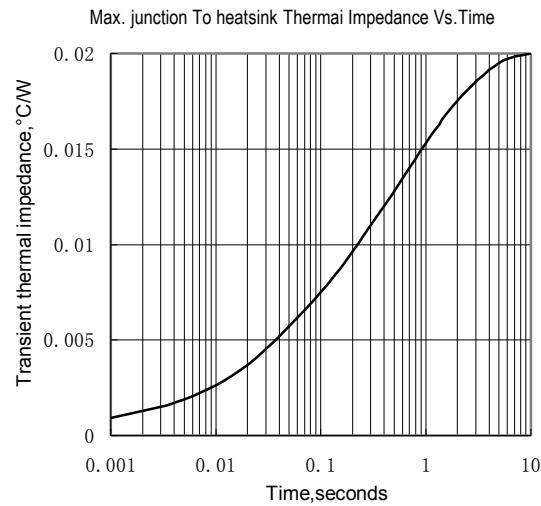


Fig.2

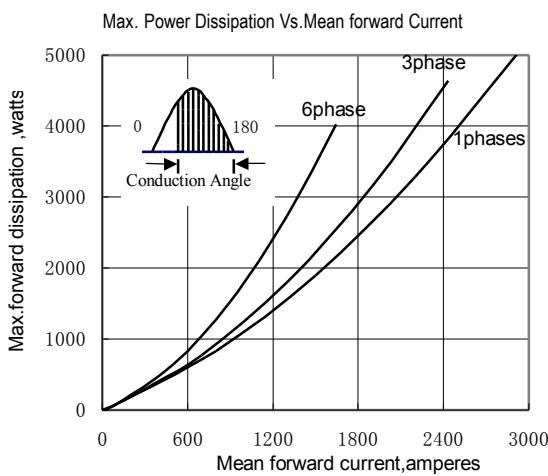


Fig.3

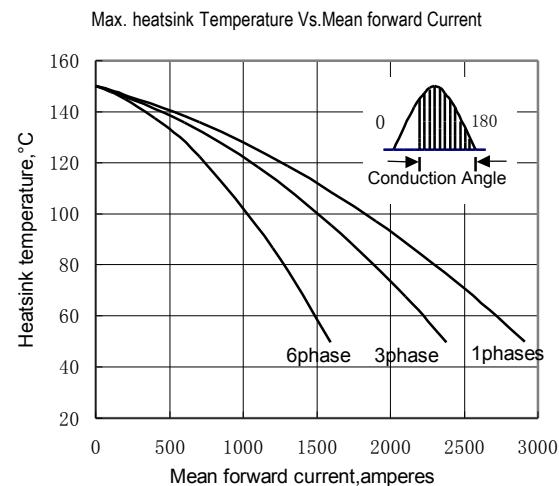


Fig.4

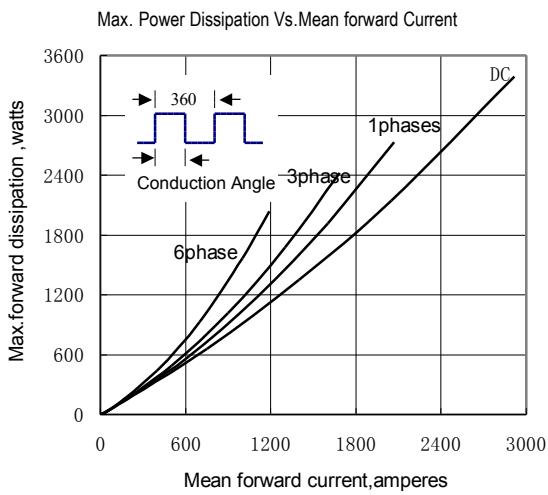


Fig.5

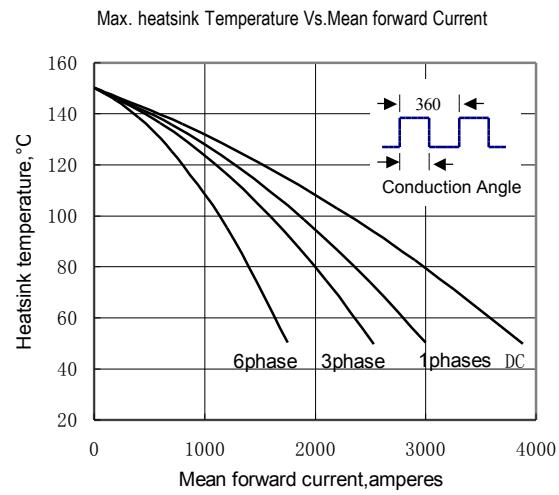


Fig.6

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